17SEP2015 Rev.B

PUSH-PUSH Micro SIM CONNECTOR

1.Introduction

1.1 Objective

Testing was performed on the PUSH-PUSH Micro SIM CONNECTOR to determine

if it meets the requirement of product specification, 108-140068

1.2 Scope

This report covers the electrical, mechanical and environment performance requirements of the PUSH-PUSH Micro SIM CONNECTOR.

The qualification testing was performed between 20JUN2014 and 13AUG2014.

The following documents form a part of this specification to the extent specified herein. In the event of conflict between the requirements of this specification and the product drawing, the product drawing shall take precedence. In the event of conflict between the requirements of this specification and the referenced documents, this specification shall take precedence.

1.3 Conclusion

The PUSH-PUSH Micro SIM CONNECTOR meets the electorical, mechanical and environmental performance requirements of product specification, 108-140068

1.4 Product description

The PUSH-PUSH Micro SIM CONNECTOR is designed to make a connection between a Subscriber Identity Module (SIM) and printed circuit board.

1.5 Test samples

Samples were taken randomly from prototype samples. The follwing samples were used.

Part number	Description
2822541-1	PUSH-PUSH Micro SIM CONNECTOR
2229116-2	PUSH-PUSH Micro SIM CONNECTOR SHORT DIP TYPE
TB-1693	Test card

Fig.1

* Trademark



2. Test contents

Para.	Test items	Requirements	Judgment
2.1	Examination of product	Visual inspection No physical damage	Acceptable
		Electrical requirements	
2.2	Contact resistance (low level)	 Initial contact resistance: 150mΩ Max. Max contact resistance after group testing: 150mΩ Max. Contact resistance includes also the bulk resistance due to terminal After any environmental test for every contact Detection switch: 500mΩMax. Mate connector with dry circuit (20mV, 100mA Max.) 4-wire measurement required Measure resistance with minimum thickness memory card (or PWB) 	Acceptable
2.3	Insulation resistance	•1000MΩ Min. •Unmated connector with 500 VDC between adjacent contact for 1 minute (IEC 60512-3-1)	Acceptable
2.4	Dielectric strength	No voltage breakdown Unmated connector with 500 VAC between adjacent contact for 1 minute (IEC 60512-3-1)	Acceptable
2.5	Temperature rise	·30°C Max. under loaded rating current (0.5A) ·Contacts series-,apply test current of loaded rating current of the circuit ·Measure the temperature rising by probing on soldered areas of contacts ·After the temperature becomes stabilized deduct ambient temperature from the measured	Acceptable

Fig. 2 (CONT.)

Rev. B 2 of 10



Para.	Test items	Requirements	Judgment
		Mechanical requirements	
2.6	Durability (1500 cycle)	Contact resistance: 150mΩ Max. No mechanical damage for connector as well as Micro SIM cards Eject length: 2.8mm REF. Mating contacts at 4-10 cycles/minute, including pause between mate/unmate to 1500 cycles After every 10 (Max.) cycles blow with dry air	Acceptable
2.7	Wrongly insertion test card upside down	·25N Min. ·No mechanical damage ·The card cannot be stuck in the reader	Acceptable
		Environmental requirements	
2.8	Dry cold (steady state)	No mechanical damage No change to performance Contact resistance: 150mΩ Max.(Data) -40°C for 96hours; recovery period 1-2hours under ambient atmospheric conditions (IEC60068-2-1Ab)	Acceptable
2.9	Dry heat (steady state)	No mechanical damage No change to performance Contact resistance: 150mΩ Max.(Data) +85°C for 96 hours; recovery period 1-2hours under ambient atmospheric conditions (IEC60068-2-2Bb)	Acceptable
2.10	Thermal shock (change of temperature)	 No mechanical damage No change to performance Contact resistance: 150mΩ Max.(Data) 25 cycle at T_a = -55 °C for 0.5 hours; then change of temp=25°C Max. 5 minute; then T_b=+85°C for 0.5 hours; then cool to ambient Recovery: 2 hours at ambient atmosphere (IEC60068-2-14 Test Na) 	Acceptable
2.11	Humidity - temperature cycling	 No change to performance Contact resistance:150 mΩ Max. Insulation Resistance should be measured Measure the resistance without opening the mating after test Temp 25-65°C, RH 50-80% for 10 cycles Cold shock -10°C performed (EIA-364-31) 	Acceptable

Fig. 2 (CONT.)

Rev. B 3 of 10



Para.	Test items	Requirements	Judgment
2.12	SO ₂ gas	 No mechanical damage No change to performance Contact resistance: 150mΩ Max. (Data) 10±3ppm, Damp 75% at 40±2°C, 48hours 	Acceptable
2.13	Vibration (random)	 Discontinuity during testing 1 µs with all contacts in series No mechanical damage No change to performance Contact resistance: 150mΩ Max. Frequency:10 - 100 Hz; 3 m²/s³ (0.0132 g²/Hz);100 - 500 Hz; -3dB/Oct. for: 3 x 60 minute (X- Y- and Z-axis) (IEC60068-2-64Fh) 	Acceptable
2.14	Shock (specified pulse)	 Discontinuity during testing 1 µs with all contacts in series No mechanical damage No change to performance Contact resistance: 150mΩ Max. Pulse shape=half sine Peak acceleration=50G Duration of pulse=11ms Apply 3 shocks in each direction along the 3 mutually perpendicular axes (18 shocks) (IEC60068-2-27Ea) 	Acceptable

Fig. 2 (CONT.)

Rev. B 4 of 10



3. Product qualification test sequence

	Test Examination					Test (Group			
Para.	rest Examination	1	2	3	4	5	6	7	8	9
3.5.1	Examination of product	1,7	1,5	1,5	1,5	1,5	1,5	1,6	1,3	1,3
3.5.2	Contact resistance (low level)		2,4	2,4	2,4	2,4	2,4	2,5		
3.5.3	Insulation resistance	2,5								
3.5.4	Dielectric strength	3,6								
3.5.5	Temperature rise								2	
3.5.6	Durability						3			
3.5.7	Wrongly Insertion test card upside down									2
3.5.8	Dry cold (steady state)		3							
3.5.9	Dry heat (steady state)			3						
3.5.10	Thermal shock (change of temperature)				3					
3.5.11	Humidity-temperature cycling	4								
3.5.12	SO₂ gas					3				
3.5.13	Vibration (random)							3		
3.5.14	Shock (specified pulse)							4		

⁽a) Numbers indicate sequence in which the tests are performed.

Fig. 3

Rev. B 5 of 10



4. Test results

Test item	Unit		Result	Requirements	Judge -ment
		Ν	Max. Min. Ave. Sig.	•	
			Test group 1		
Examination of product	-	5	No abnormalities	No abnormalities	Accept -able
Insulation resistance	Ω	5	154000000MΩ Min.	1000MΩ Min.	Accept -able
Dielectric strength	-	5	No abnormalities	No abnormalities	Accept -able
Insulation resistance after Humidity-temperature cycling	Ω	5	6180000MΩ Min.	1000MΩ Min.	Accept -able
Dielectric strength after Humidity-temperature cycling	-	5	No abnormalities	No abnormalities	Accept -able
Examination of product after Humidity-temperature cycling	-	5	No abnormalities	No abnormalities	Accept -able

Test item	Test item				Resu	lt		Requirements	Judge
			Ν	Max.	Min.	Ave.	Sig.	- 4	-ment
				Tes	st group	2			
Examination of product			5	No abr	normaliti	es		No abnormalities	Accept -able
Contact resistance	Contact	mΩ	30	13.2	5.6	9.4	2.17	150mΩ Max.(initial) Detection switch	Accept -able
Contact resistance	Detection switch	11152	5	151.1	127.3	139.1	10.56	:500mΩMax.	
Contact resistance	Contact	mΩ	30	13.2	6.1	9.7	2.19	150mΩ Max.(final) Detection switch	Accept
after dry cold	Detection switch	11152	5	161.3	130.3	145.6	12.55	:500mΩMax.	-able
Examination of product after dry cold		-	5	No abr	normaliti	es		No abnormalities	Accept -able

Group 1,2 (End)

Rev. B 6 of 10



Test item	Test item				Resu	lt		Requirements	Judge
1000 110111		Unit	Ν	Max.	Min.	Ave.	Sig.	r toquilomonio	-ment
				Tes	st group	3			
Examination of product			5 No abnormalities					No abnormalities	Accept -able
Contact resistance	Contact	mΩ	30	13.8	6.2	10.0	2.41	150mΩ Max.(initial) Detection switch	Accept -able
Oomact resistance	Detection switch		5	171.4	147.5	160.8	9.34	:500mΩMax.	
Contact resistance	Contact	mΩ	30	20.9	7.5	13.4	3.57	150mΩ Max.(final) Detection switch	Accept
after dry heat	Detection switch	11152	5	176.6	139.6	157.1	15.26	:500mΩMax.	-able
Examination of product after dry heat			5	No abr	normaliti	es		No abnormalities	Accept -able

Test item	Test item				Resu	lt		Requirements	Judge
100(110111		Unit	Ν	Max.	Min.	Ave.	Sig.		-ment
				Tes	st group	4			
Examination of product			5	No abr	normaliti	es		No abnormalities	Accept -able
Contact resistance	Contact	mΩ	30	14.3	6.9	10.3	2.45	150mΩ Max.(initial) Detection switch :500mΩMax.	Accept -able
Oontact resistance	Detection switch	11152	5	162.9	156.3	158.9	2.76		
Contact resistance	Contact	mΩ	30	16.7	7.7	11.8	2.55	150mΩ Max.(final) Detection switch	Accept
after thermal shock	Detection switch	11132	5	186.1	140.0	163.0	20.24	:500mΩMax.	-able
Examination of product after thermal shock		-	5	No abr	normaliti	es		No abnormalities	Accept -able

Group 3,4 (End)

Rev. B 7 of 10



Test item	Test item				Resu	lt		Requirements	Judge	
100(110111		Unit	N	Max.	Min.	Ave.	Sig.	rioquiomonio	-ment	
			Test group 5							
Examination of product			5	No abr	normaliti	es		No abnormalities	Accept -able	
Contact resistance	Contact	mΩ	30	13.4	5.8	9.8	2.10	150mΩ Max.(initial) Detection switch	Accept	
Contact resistance	Detection switch	11152	5	162.3	137.2	146.2	10.26	:500mΩMax.	-able	
Contact resistance	Contact	mΩ	30	19.3	7.0	11.1	2.78	150mΩ Max.(final) Detection switch	Accept	
after SO ₂ gas	Detection switch	111122	5	178.7	153.7	168.1	10.04	:500mΩMax.	-able	
Examination of product SO ₂ gas			5	No abr	normaliti	es		No abnormalities	Accept -able	

Test item		Unit	N	Max.	Resu Min.	lt Ave.	Sig.	Requirements	Judge -ment
					st group				
Examination of product		-	5	No abnormalities				No abnormalities	Accept -able
Contact resistance	Contact	mΩ	30	12.6	5.4	9.7	2.39	150mΩ Max.(initial) Detection switch	Accept
Contact resistance	Detection switch	11152	5	148.3	138.3	143.5	4.25	:500mΩMax.	-able
Durability		-	5	No abr	normaliti	es		No abnormalities	Accept -able
Contact resistance	Contact	mΩ	30	18.6	5.4	10.3	3.17	150mΩ Max.(final) Detection switch	Accept
after durability	Detection switch	111122	5	146.8	132.8	138.5	5.94	:500mΩMax.	-able
Examination of prod after durability	uct	-	5	No abr	normaliti	es		No abnormalities	Accept -able

Group 5,6 (End)

Rev. B 8 of 10



Test item		Unit	N	Max.	Resu Min.	lt Ave.	Sig.	Requirements	Judge -ment	
			ı	Tes	st group	7				
Examination of product		-	5	No abr	normaliti	es		No abnormalities	Accept -able	
Contact resistance	Contact	mΩ	30	13.2	6.1	10.2	2.23	150mΩ Max.(initial) Detection switch	Accept	
Somati resistance	Detection switch	11152	5	150.1	137.6	144.3	4.91	:500mΩMax.	-able	
Vibration (random)		-	5	No abr	normaliti	es		1µs Max.	Accept -able	
Shock (specified pul	se)	-	5	No abr	normaliti	es		1µs Max.	Accept -able	
Contact resistance after vibration and	Contact	mΩ	30	15.1	6.4	10.1	2.37	150mΩ Max.(final) Detection switch	Accept	
shock	Detection switch	11152	5	164.7	146.6	154.5	6.98	:500mΩMax.	-able	
Examination of product after vibration and shock		-	5	No abr	normaliti	es		No abnormalities	Accept -able	

Test item	Unit						Requirements	Judge			
		N	Max.	Min.	Ave.	Sig.	•	-ment			
Test group 8											
Examination of product	-	5	No abnormalities				No abnormalities	Accept -able			
Temperature rise	°C	5	1.45	1.40	1.42	0.027	30°C Max.	Accept -able			
Examination of product after temperature rise	-	5	No abnormalities				No abnormalities	Accept -able			

Group 7,8 (End)

Rev. B 9 of 10



Test item	Unit	N	Result	Requirements	Judge -ment					
Test group 9										
Examination of product	1	5	No abnormalities	No abnormalities	Accept -able					
Wrongly insertion test card upside down	1	5	No mechanical damage at 25N (broken force : 72.1N Min)	25N Min.	Accept -able					
Examination of product	1	5	No abnormalities	No abnormalities	Accept -able					

Group 9 (End)

Rev. B 10 of 10